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出货

## Programmable Oscillator/Timer

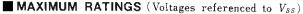
The HD14541B programmable timer consists of a 16-stage binary counter, an integrated oscillator for use with an external capacitor and two resistors, an automatic power-on reset circuit, and output control logic. Timing is initialized by turning on power, whereupon the power-on reset is enabled and initializes the counter, within the specified  $V_{DD}$  range. With the power already on, an external reset pulse can be applied. Upon release of the initial reset command, the oscillator will oscillate with a frequency determined by the external RC network. The 16-stage counter divides the oscillator frequency  $(f_{osc})$  with the n<sup>th</sup> stage frequency being  $f_{osc}/2^n$ .

#### **FEATURES**

- Available Outputs  $2^8$ ,  $2^{10}$ ,  $2^{13}$  or  $2^{16}$
- Increments on Positive Edge Clock Transitions
- Low Symmetrical Output Resistance (typically  $100\Omega @15V$ )
- Built-in Low Power RC Oscillator (±2% accuracy over temperature range and  $\pm 10\%$  supply and  $\pm 3\%$  over processing @ < 10 kHz)
- Oscillator Frequency Range = DC to 100kHz
- Oscillator May Be Bypassed if External Clock is Available (Apply external clock to Pin 3)
- Automatic Reset Initializes All Counters When Power Turns On (Limits-Vpn from 8.5V to 18V when enabled)
- External Master Reset Totally Independent of Automatic Reset Operation
- Operates as  $2^n$  Frequency Divider or Single Transition Timer
- Q/Q Select Provides Output Logic Level Flexibility
- Reset (auto or master) Disables Oscillator During Resetting to Provide No Active Power Dissipation
- Clock Conditioning Circuit Permits Operation with Very Slow Clock Rise and Fall Times WWW.DZSC.COM
- Supply Voltage Range = 3 to 18V

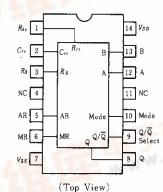


Characteristic	Symbol	Value	Unit	
DC Supply Voltage	VDD	$-0.5 \sim +18$	V	
Input/Output Voltage	Vin, Voul	$-0.5 \sim V_{DD} + 0.5$	v	
DC Current Drain per Input Pin	Lin	±10	mA	
DC Current Drain per Output Pin	Іол, Іон	± 45	mA	
Operating Temperature Range	TA	-40~+85	ĩ	
Storage Temperature Range	Tata	-65~+150	°C	
Power Dissipation	PD	300	mW	





PIN ARRANGEMENT



#### TRUTH TABLE

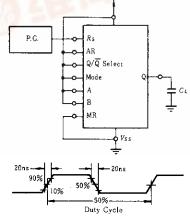
Pin	State				
Fin	0	1			
5	Auto Reset Operating	Auto Reset Disabled			
6	Timer Operational	Master Reset ON			
9	Output Initially Low After Reset	Output Initially High After Reset			
10	Single Cycle Mode	Recycle Mode			

#### FREQUENCY SELECTTION TABLE

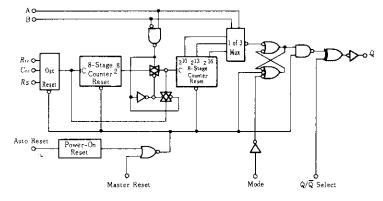
A	в	Number of Counter Stages	Count 2 <sup>n</sup>
0	0	13	8192
0	1	10	1024
1	0	8	256
1	1	16	65536

#### POWER DISSIPATION TEST CIRCUIT AND WAVEFORM





## BLOCK DIAGRAM



## ELECTRICAL CHARACTERISTICS

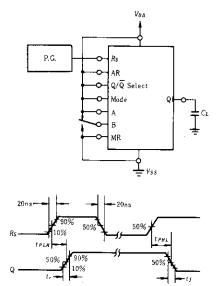
Characteristic	Symbol		Test Conditions	-4	0°C		25°C		8	5°C	Unit
Characteristic	Сушьог	$V_{DD}(V)$	Test Conditions	min	max	min	typ	max	min	max	Unit
		5.0	$V_{in} = V_{DD}$ or 0	-	0.05		0	0.05		0.05	V.
	Vol	10		-	0.05	—	0	0.05	-	0.05	
Output Voltage		15			0.05	—	0	0.05	_	0.05	
output fortage		5.0		4.95	—	4.95	5.0	_	4.95	—	
	Voн	10	$V_{in} = 0$ or $V_{DD}$	9.95	-	9.95	10	-	9.95	_	v
		15		14.95	—	14.95	15		14.95	—	
		5.0	$V_{out} = 4.5 \text{ or } 0.5 \text{ V}$	-	1.5	-	2.25	1.5		1.5	v
	VIL	10	$V_{out} = 9.0 \text{ or } 1.0 \text{ V}$		3.0		4.50	3.0	—	3.0	
Input Voltage		15	$V_{out} = 13.5$ or $1.5 \mathrm{V}$	-	4.0	—	6.75	4.0	_	4.0	
input voltage		5.0	$V_{oxi} = 0.5 \text{ or } 4.5 \text{ V}$	3.5		3.5	2.75		3.5		v
	V <sub>IH</sub>	10	$V_{out} = 1.0 \text{ or } 9.0 \text{ V}$	7.0		7.0	5.50	_	7.0	_	
		15	$V_{out} = 1.5$ or $13.5 V$	11.0	· —	11.0	8.25	—	11.0	—	
	- · · · ·	5.0	$V_{OH} = 2.5 \mathrm{V}$	-5.1		-4.27	-12.83		-3.5	-	mA
	Іон	10	$V_{OH} = 9.5 \mathrm{V}$	-2.69		-2.25	-6.75	_	-1.85		
0		15	$V_{0H} = 13.5 \mathrm{V}$	-10.5	—	-8.8	-26.33		-7.22		
Output Drive Current		5.0	$V_{OL} = 0.4 \mathrm{V}$	1.24	-	1.04	3,12	-	0.85		mA
	Ioz	10	$V_{0L} = 0.5 V$	3.18	_	2.66	8.0	_	2.18	_	
		15	$V_{0L} = 1.5 \mathrm{V}$	12.4		10.4	31.2	. <u>-</u>	8.50		
Input Current	Iin	15			±0.3		±0.00001	±0.3	—	$\pm 1.0$	μA
Input Capacitance	Cin		$V_{in} = 0$	-		_	5.0	7.5	_	-	pF
		5.0	Zero Signal, per Package	-	20	-	0.005	20	_	150	
Quiescent Current	IDD	10		_	40		0.010	40	-	300	μA
		15 per		_	80	-	0.015	80		600	
Auto Resct Quiescent Current	ļ	5.0		-	200		7	200		1200	. μA
	IDDR	10	Pin 5 is low		250		30	250	-	1500,	
		15			500	- 1	82	500	-	2000	
Total Supply Current*	Ιτ	5.0	Dynamic +IDD,	-	- 1	_	0.4	-	_	-	
		10	per Gate	—	-	-	0.8	_		—	μA
		15	$C_L = 50 \text{pF}, f = 1 \text{kHz}$		-	-	1.2	_	_	-	]

\* To calculate total supply current at frequency other than 1kHz.

 $@V_{DD} = 5.0V I_{7} = (0.4 \ \mu A/kHz)f + I_{00}, @V_{DD} = 10V I_{7} = (0.8 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 15V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 15V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 15V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = 10V I_{7} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{DD} = (1.2 \ \mu A/kHz)f + I_{DD}, @V_{D$ 

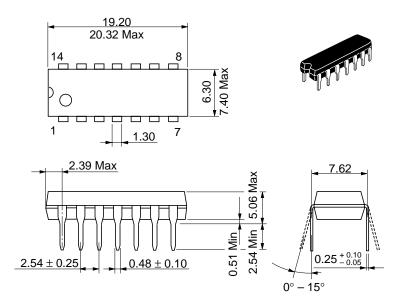
## SWITCHING TIME TEST CIRCUIT

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## **SWITCHING CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ , $Ta = 25^{\circ}\text{C}$ )

Charac	teristic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	тах	Unit
Output Rise Time		t,	5.0		180	400	ns
			10	_	90	200	
			15	_	65	160	
			5.0	_	100	200	
Output Fall Time		$t_f$	10	_	50	100	ns
			15	_	37	80	
			5.0	—	3.5	10.5	
	Clock to Q (2 <sup>8</sup> Output)		10	_	1.25	3.8	
Propagation Delay Time		tpln,	15	_	0.9	2.9	]
Tropagation Delay Thire		t <sub>PHL</sub>	5.0	_	6.0	18	_ μs
	Clock to $Q(2^{16} \text{ Output})$		10	_	3.5	10	
	<i>n</i>		15	—	2.5	7.5	
Clock Pulse Width			5.0	900	300	—	ns
		$PW_c$	10	300	100		
······			15	225	85	-	1
Clock Frequency			5.0	_	1.5		
		PRF	10	-	4.0		MHz
			15	_	6.0		1
Minimum Master Reset Pulse Width			5.0	900	300		
		PWMR	10	300	100	-	_ns
			15	225	85	_	1



Unit: mm

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### Hitachi, Ltd.

URL

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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#### For further information write to:

Japan

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1> (408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180 Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsu Kowloon, Hong Kong Tel: .4852- (2) 735 9218 Fax: .4852- (2) 730 0281 Telex: .40815 HITEC HX

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